



DMP3018SSS

Product Summary

BV _{DSS}	R _{DS(ON)} Max	I _D Max T _A = +25°C		
-30V	12mΩ @ V _{GS} = -10V	-10.5A		
	21mΩ @ V _{GS} = -4.5V	-8.0A		

Description and Applications

This MOSFET is designed to minimize the on-state resistance (R_{DS(ON)}) and yet maintain superior switching performance, making it ideal for high efficiency power management applications.

- Backlighting
- **Power Management Functions**
- **DC-DC Converters**

P-CHANNEL ENHANCEMENT MODE MOSFET

Features and Benefits

- Low On-Resistance
- Low Input Capacitance
- Fast Switching Speed
- ESD Protected Gate
- 100% Unclamped Inductive Switching (UIS) Test in Production -Ensures More Reliable and Robust End Application
- Totally Lead-Free & Fully RoHS Compliant (Notes 1 & 2)
- Halogen and Antimony Free. "Green" Device (Note 3)

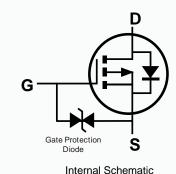
Mechanical Data

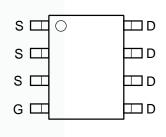
- Case: SO-8
- Case Material: Molded Plastic, "Green" Molding Compound. UL Flammability Classification Rating 94V-0
- Moisture Sensitivity: Level 1 per J-STD-020
- Terminal Connections Indicator: See Diagram Below
- Terminals: Finish Matte Tin Annealed Over Copper Lead Frame. Solderable per MIL-STD-202, Method 208 03
- Weight: 0.074 grams (Approximate)



Top View

SO-8





Top View

Pin Configuration

Ordering Information (Note 4)

	Part Number	Case	Packaging			
DMP3018SSS-13		SO-8	2,500/Tape & Reel			
Notes:	1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.					

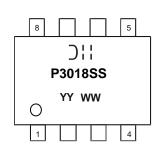
1. No purposely added lead. Fully EU Directive 2002/95/EC (RoHS), 2011/65/EU (RoHS 2) & 2015/863/EU (RoHS 3) compliant.

2. See https://www.diodes.com/quality/lead-free/ for more information about Diodes Incorporated's definitions of Halogen- and Antimony-free, "Green" and Lead-free.

3. Halogen- and Antimony-free "Green" products are defined as those which contain <900ppm bromine, <900ppm chlorine (<1500ppm total Br + Cl) and <1000ppm antimony compounds.

4. For packaging details, go to our website at https://www.diodes.com/design/support/packaging/diodes-packaging/.

Marking Information



) | | = Manufacturer's Marking P3018SS = Product Type Marking Code YYWW = Date Code Marking YY or \overline{YY} = Year (ex: 19 = 2019) WW = Week (01 to 53)



Maximum Ratings ($@T_A = +25^{\circ}C$, unless otherwise specified.)

Characteristic	Symbol	Value	Unit		
Drain-Source Voltage	V _{DSS}	-30	V		
Gate-Source Voltage	V _{GSS}	±25	V		
Continuous Drain Current (Note 6) V _{GS} = -10V	Steady State	T _A = +25°C T _A = +70°C	ID	-10.5 -8.5	А
Continuous Drain Current (Note 6) V _{GS} = -10V	Steady State	T _C = +25°C T _C = +70°C	ID	-25 -20	А
Maximum Continuous Body Diode Forward Currer	ls	-20	А		
Pulsed Drain Current (10µs Pulse, Duty Cycle = 1	I _{DM}	-90	А		
Avalanche Current (Note 7) L = 1mH	las	-14	А		
Avalanche Energy (Note 7) L = 1mH	E _{AS}	104	mJ		

Thermal Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic		Symbol	Value	Unit
Total Power Dissipation (Note 5)	T _A = +25°C	PD	1.2	W
Thermal Resistance, Junction to Ambient (Note 5)	Steady State	R _{θJA}	101	°C/W
Total Power Dissipation (Note 6)	T _A = +25°C	PD	1.7	W
Thermal Resistance, Junction to Ambient (Note 6)	Steady State	R _{0JA}	73	°C/W
Total Power Dissipation (Note 6)	PD	10	W	
Thermal Resistance, Junction to Case (Note 6)	R _{ejc}	12.5	°C/W	
Operating and Storage Temperature Range	TJ, TSTG	-55 to +150	°C	

Electrical Characteristics (@T_A = +25°C, unless otherwise specified.)

Characteristic	Symbol	Min	Тур	Max	Unit	Test Condition	
OFF CHARACTERISTICS (Note 8)	•					·	
Drain-Source Breakdown Voltage	BV _{DSS}	-30	—	_	V	$V_{GS} = 0V, I_D = -250 \mu A$	
Zero Gate Voltage Drain Current	I _{DSS}	—	—	-1	μA	$V_{DS} = -24V, V_{GS} = 0V$	
Gate-Source Leakage	IGSS	—	-	±10	μA	$V_{GS} = \pm 20V, V_{DS} = 0V$	
ON CHARACTERISTICS (Note 8)							
Gate Threshold Voltage	V _{GS(TH)}	-1.0	—	-3.0	V	$V_{DS} = V_{GS}$, $I_D = -250 \mu A$	
Static Drain-Source On-Resistance	Р	_	8.7	12	mΩ	V _{GS} = -10V, I _D = -11.5A	
	R _{DS(ON)}	_	14.5	21	11122	$V_{GS} = -4.5V, I_D = -8.5A$	
Diode Forward Voltage	V _{SD}	_	-0.7	-1.2	V	$V_{GS} = 0V, I_{S} = -1A$	
DYNAMIC CHARACTERISTICS (Note 9)							
Input Capacitance	C _{iss}	_	2,147		pF	− V _{DS} = -15V, V _{GS} = 0V, − f = 1.0MHz	
Output Capacitance	Coss	_	407	_	pF		
Reverse Transfer Capacitance	C _{rss}		358	_	pF		
Gate Resistance	Rg	_	24		Ω	$V_{DS} = 0V, V_{GS} = 0V, f = 1.0MHz$	
Total Gate Charge (V _{GS} = -5V)	Qg	_	28	—	nC		
Total Gate Charge (V _{GS} = -10V)	Qg	_	51	_	nC	V _{DS} = -15V, I _D = -11.5A	
Gate-Source Charge	Q _{gs}	—	6.6	_	nC		
Gate-Drain Charge	Q _{gd}	_	15	_	nC		
Turn-On Delay Time	t _{D(ON)}		7.8	_	ns		
Turn-On Rise Time	t _R	_	19.9	_	ns	$V_{DD} = -15V, V_{GS} = -10V,$	
Turn-Off Delay Time	t _{D(OFF)}		57.5	_	ns	$R_{\rm G} = 6\Omega, I_{\rm D} = -11.5A$	
Turn-Off Fall Time	t _F		42.8	_	ns		
Reverse Recovery Time	t _{RR}	—	21.5	_	ns	I _S = -11.5A, dl/dt = 100A/µs	
Reverse Recovery Charge	Q _{RR}	—	11.6	_	nC	$1s = -11.5A$, $u/dt = 100A/\mu s$	

Notes:

Device mounted on FR-4 PC board, with minimum recommended pad layout, single sided.
Device mounted on FR-4 substrate PC board, 2oz copper, with thermal bias to bottom layer 1-inch square copper plate.

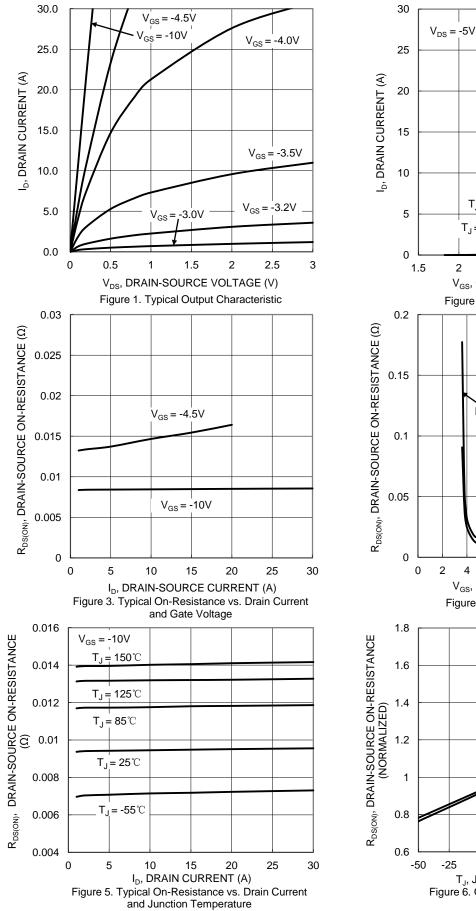
7. I_{AS} and E_{AS} ratings are based on low frequency and duty cycles to keep $T_J = +25^{\circ}C$.

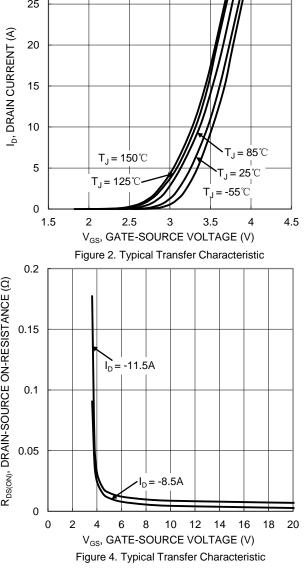
8. Short duration pulse test used to minimize self-heating effect.

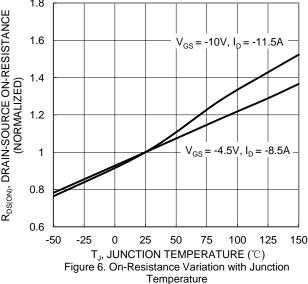
9. Guaranteed by design. Not subject to product testing.



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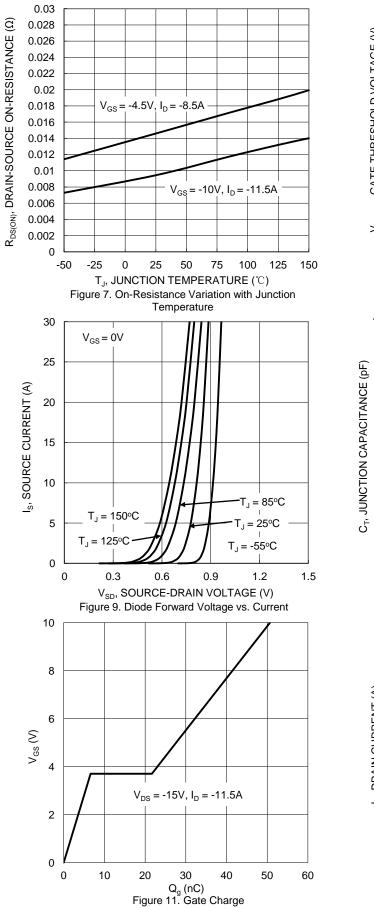


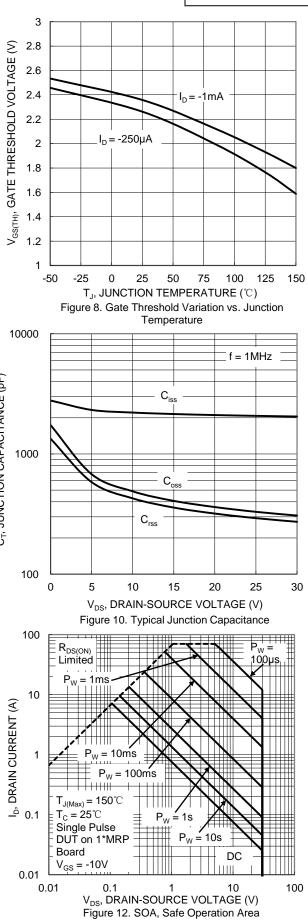




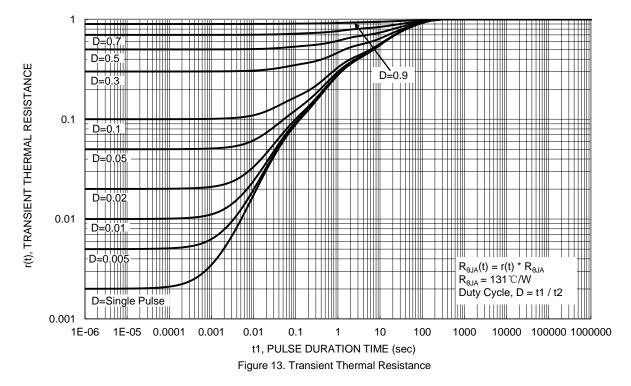
DMP3018SSS Document number: DS40423 Rev. 4 - 2













Тур

1.45

0.15

0.40

0.20

4.90

6.00

3.85

3.90 1.27

0.35

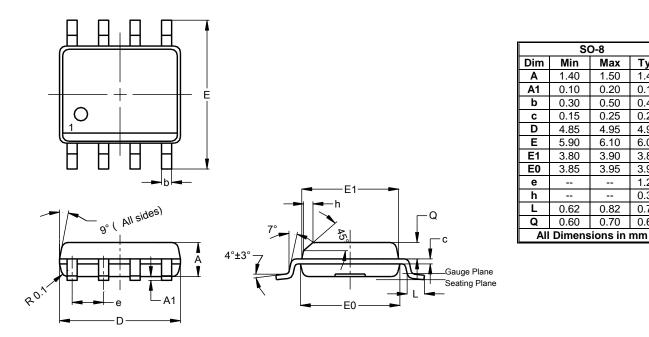
0.72

0.65

Package Outline Dimensions

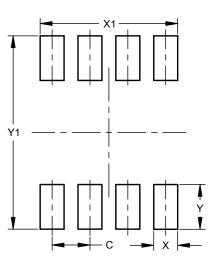
Please see http://www.diodes.com/package-outlines.html for the latest version.

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Suggested Pad Layout

Please see http://www.diodes.com/package-outlines.html for the latest version.



Dimensions	Value (in mm)
C	1.27
Х	0.802
X1	4.612
Y	1.505
Y1	6.50

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